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Fairchild Semiconductor MMBTA13

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Datasheet of MMBTA13 - TRANS NPN DARL 30V 1.2A SOT-23

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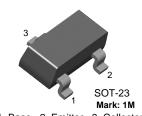


January 2005

## MMBTA13

## **NPN Darlington Transistor**

- This device is designed for applications requiring extremely high Current gain at collector Currents to 1.0A.
- Sourced from process 05.
- See MPSA14 for characteristics.



## 1. Base 2. Emitter 3. Collector

## Absolute Maximum Ratings T<sub>a</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CES</sub>	Collector-Emitter Voltage	30	V
V <sub>CBO</sub>	Collector-Base Voltage	30	V
V <sub>EBO</sub>	Emitter-Base Voltage	10	V
I <sub>C</sub>	Collector Current - Continuous	1.2	Α
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

## Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units	
Off Charac	Off Characteristics					
V <sub>(BR)CES</sub>	Collector-Emitter Breakdown Voltage	$I_C = 100\mu A, I_B = 0$	30		V	
I <sub>CBO</sub>	Collector-Cutoff Current	V <sub>CB</sub> = 30V, I <sub>E</sub> = 0		100	nA	
I <sub>EBO</sub>	Emitter-Cutoff Current	V <sub>EB</sub> = 10V, I <sub>C</sub> = 0		100	nA	
On Charac	teristics *	•				
h <sub>FE</sub>	DC Current Gain	$V_{CE} = 5.0V, I_{C} = 10mA$ $V_{CE} = 5.0, I_{C} = 100mA$	5,000 10,000			
V <sub>CE (sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 100mA, I <sub>B</sub> = 0.1mA		1.5	V	
V <sub>BE (on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 100mA,V <sub>CE</sub> = 5.0V		2.0	V	
Small Signal Characteristics						
f <sub>T</sub>	Current Gain Bandwidth Product	I <sub>C</sub> = 10mA, V <sub>CE</sub> = 10V, f = 100MHz	125		pF	

<sup>\*</sup> Pulse Test: Pulse Width≤300μs, Duty Cycle≤2%



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## Thermal Characteristics $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Max.	Units
$P_{D}$	Total Device Dissipation Derate above 25°C	350 2.8	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

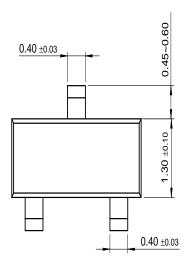
<sup>\*</sup> Device mounted on FR-4PCB 1.6"  $\times$  1.6"  $\times$  0.06".

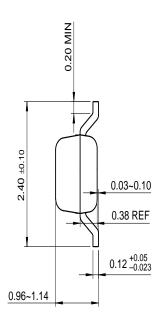


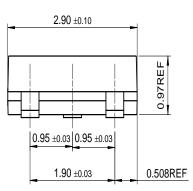
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## **Mechanical Dimensions**

## **SOT-23**







Dimensions in Millimeters



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### **Definition of Terms**

Datasheet Identification	Product Status	Definition
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